Microchip Technology - PIC16HV616-E/P Datasheet

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Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	20MHz
Connectivity	-
Peripherals	Brown-out Detect/Reset, POR, WDT
Number of I/O	11
Program Memory Size	3.5KB (2K x 14)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128 x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 5V
Data Converters	A/D 8x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Through Hole
Package / Case	14-DIP (0.300", 7.62mm)
Supplier Device Package	14-PDIP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16hv616-e-p

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PIC16F610/16HV610 16-Pin Diagram (QFN)



TABLE 3:	PIC16F610/16HV610	16-PIN SUMMARY

I/O	Pin	Comparators	Timers	Interrupts	Pull-ups	Basic
RA0	12	C1IN+	-	IOC	Y	ICSPDAT
RA1	11	C12IN0-		IOC	Y	ICSPCLK
RA2	10	C1OUT	TOCKI	INT/IOC	Y	—
RA3 ⁽¹⁾	3	—	_	IOC	Y(2)	MCLR/VPP
RA4	2	—	T1G	IOC	Y	OSC2/CLKOUT
RA5	1	—	T1CKI	IOC	Y	OSC1/CLKIN
RC0	9	C2IN+	—	—	—	—
RC1	8	C12IN1-		—		—
RC2	7	C12IN2-	—	—	_	—
RC3	6	C12IN3-		—	—	_
RC4	5	C2OUT	_	—	—	—
RC5	4	—		—	_	_
—	16	—	_	—	_	Vdd
—	13					Vss

Note 1: Input only.

2: Only when pin is configured for external MCLR.

2.2.2.1 STATUS Register

The STATUS register, shown in Register 2-1, contains:

- the arithmetic status of the ALU
- · the Reset status

-n = Value at POR

• the bank select bits for data memory (RAM)

The STATUS register can be the destination for any instruction, like any other register. If the STATUS register is the destination for an instruction that affects the Z, DC or C bits, then the write to these three bits is disabled. These bits are set or cleared according to the device logic. Furthermore, the TO and PD bits are not writable. Therefore, the result of an instruction with the STATUS register as destination may be different than intended.

For example, CLRF STATUS, will clear the upper three bits and set the Z bit. This leaves the STATUS register as `000u uluu' (where u = unchanged).

It is recommended, therefore, that only BCF, BSF, SWAPF and MOVWF instructions are used to alter the STATUS register, because these instructions do not affect any Status bits. For other instructions not affecting any Status bits, see the **Section 13.0 "Instruction Set Summary"**.

- Note 1: Bits IRP and RP1 of the STATUS register are not used by the PIC16F610/616/16HV610/616 and should be maintained as clear. Use of these bits is not recommended, since this may affect upward compatibility with future products.
 - 2: The <u>C</u> and <u>DC</u> bits operate as a Borrow and Digit Borrow out bit, respectively, in subtraction. See the SUBLW and SUBWF instructions for examples.

x = Bit is unknown

REGISTER 2-1: STATUS: STATUS REGISTER

'1' = Bit is set

Reserved	Reserved	R/W-0	R-1	R-1	R/W-x	R/W-x	R/W-x
IRP	RP1	RP0	TO	PD	Z	DC	С
bit 7							bit 0
Legend:							
R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'							

'0' = Bit is cleared

bit 7	IRP: This bit is reserved and should be maintained as '0'
bit 6	RP1: This bit is reserved and should be maintained as '0'
bit 5	RP0: Register Bank Select bit (used for direct addressing) 1 = Bank 1 (80h – FFh) 0 = Bank 0 (00h – 7Fh)
bit 4	TO: Time-out bit
	 1 = After power-up, CLRWDT instruction or SLEEP instruction 0 = A WDT time-out occurred
bit 3	PD: Power-down bit 1 = After power-up or by the CLRWDT instruction 0 = By execution of the SLEEP instruction
bit 2	Z: Zero bit 1 = The result of an arithmetic or logic operation is zero 0 = The result of an arithmetic or logic operation is not zero
bit 1	DC: Digit Carry/Borrow bit (ADDWF, ADDLW, SUBLW, SUBWF instructions), For Borrow, the polarity is reversed. 1 = A carry-out from the 4th low-order bit of the result occurred 0 = No carry-out from the 4th low-order bit of the result
bit 0	C : Carry/Borrow bit ⁽¹⁾ (ADDWF, ADDLW, SUBLW, SUBWF instructions) 1 = A carry-out from the Most Significant bit of the result occurred 0 = No carry-out from the Most Significant bit of the result occurred
Note 1:	For Borrow, the polarity is reversed. A subtraction is executed by adding the two's complement of the second operand. For rotate (RRF, RLF) instructions, this bit is loaded with either the high-order or low-order bit of the source register.

NOTES:

4.2.4.4 RA3/MCLR/VPP

Figure 4-3 shows the diagram for this pin. The RA3 pin is configurable to function as one of the following:

- a general purpose input
- as Master Clear Reset with weak pull-up
- High Voltage Programming voltage input





9.2 ADC Operation

9.2.1 STARTING A CONVERSION

To enable the ADC module, the ADON bit of the ADCON0 register must be set to a '1'. Setting the GO/ DONE bit of the ADCON0 register to a '1' will start the analog-to-digital conversion.

Note:	The GO/DONE bit should not be set in the							
	same instruction that turns on the ADC.							
	Refer to Section 9.2.6 "A/D Conversion							
	Procedure".							

9.2.2 COMPLETION OF A CONVERSION

When the conversion is complete, the ADC module will:

- Clear the GO/DONE bit
- Set the ADIF flag bit
- Update the ADRESH:ADRESL registers with new conversion result

9.2.3 TERMINATING A CONVERSION

If a conversion must be terminated before completion, the GO/DONE bit can be cleared in software. The ADRESH:ADRESL registers will not be updated with the partially complete analog-to-digital conversion sample. Instead, the ADRESH:ADRESL register pair will retain the value of the previous conversion. Additionally, a 2 TAD delay is required before another acquisition can be initiated. Following this delay, an input acquisition is automatically started on the selected channel.

Note:	A device Reset forces all registers to their								
	Reset state. Thus, the ADC module is								
	turned off and any pending conversion is								
	terminated.								

9.2.4 ADC OPERATION DURING SLEEP

The ADC module can operate during Sleep. This requires the ADC clock source to be set to the FRC option. When the FRC clock source is selected, the ADC waits one additional instruction before starting the conversion. This allows the SLEEP instruction to be executed, which can reduce system noise during the conversion. If the ADC interrupt is enabled, the device will wake-up from Sleep when the conversion completes. If the ADC interrupt is disabled, the ADC module is turned off after the conversion completes, although the ADON bit remains set.

When the ADC clock source is something other than FRC, a SLEEP instruction causes the present conversion to be aborted and the ADC module is turned off, although the ADON bit remains set.

9.2.5 SPECIAL EVENT TRIGGER

The ECCP Special Event Trigger allows periodic ADC measurements without software intervention. When this trigger occurs, the GO/DONE bit is set by hardware and the Timer1 counter resets to zero.

Using the Special Event Trigger does not ensure proper ADC timing. It is the user's responsibility to ensure that the ADC timing requirements are met.

See Section 10.0 "Enhanced Capture/Compare/ PWM (With Auto-Shutdown and Dead Band) Module (PIC16F616/16HV616 Only)" for more information.

9.2.6 A/D CONVERSION PROCEDURE

This is an example procedure for using the ADC to perform an analog-to-digital conversion:

- 1. Configure Port:
 - Disable pin output driver (See TRIS register)
 - Configure pin as analog
- 2. Configure the ADC module:
 - Select ADC conversion clock
 - Configure voltage reference
 - Select ADC input channel
 - Select result format
 - Turn on ADC module
- 3. Configure ADC interrupt (optional):
 - Clear ADC interrupt flag
 - Enable ADC interrupt
 - · Enable peripheral interrupt
 - Enable global interrupt⁽¹⁾
- 4. Wait the required acquisition time⁽²⁾.
- 5. Start conversion by setting the GO/DONE bit.
- 6. Wait for ADC conversion to complete by one of the following:
 - Polling the GO/DONE bit
 - Waiting for the ADC interrupt (interrupts enabled)
- 7. Read ADC Result
- 8. Clear the ADC interrupt flag (required if interrupt is enabled).
 - **Note 1:** The global interrupt may be disabled if the user is attempting to wake-up from Sleep and resume in-line code execution.
 - 2: See Section 9.3 "A/D Acquisition Requirements".

U-0	R/W-0	R/W-0	R/W-0	U-0	U-0	U-0	U-0		
_	ADCS2	ADCS1	ADCS0	—	—	—	—		
bit 7							bit 0		
Legend:									
R = Readable bi	t	W = Writable bi	t	U = Unimpleme	ented bit, read as	s 'O'			
-n = Value at PC	R	'1' = Bit is set		'0' = Bit is clear	red	x = Bit is unkno	own		
bit 7	Unimplemente	ed: Read as '0'							
bit 6-4	ADCS<2:0>: A	/D Conversion C	lock Select bits						
	000 = Fosc/2								
	001 = Fosc/8								
	010 = Fosc/32								
	x11 = FRC (clock derived from a dedicated internal oscillator = 500 kHz max)								
	100 = FOSC/4								
	101 = FOSC/16								
	110 = Fosc/64								
bit 3-0	Unimplemente	ed: Read as '0'							

REGISTER 9-2: ADCON1: A/D CONTROL REGISTER 1

10.4.2.1 Direction Change in Full-Bridge Mode

In the Full-Bridge mode, the P1M1 bit in the CCP1CON register allows users to control the forward/reverse direction. When the application firmware changes this direction control bit, the module will change to the new direction on the next PWM cycle.

A direction change is initiated in software by changing the P1M1 bit of the CCP1CON register. The following sequence occurs four Timer2 cycles prior to the end of the current PWM period:

- The modulated outputs (P1B and P1D) are placed in their inactive state.
- The associated unmodulated outputs (P1A and P1C) are switched to drive in the opposite direction.
- PWM modulation resumes at the beginning of the next period.

See Figure 10-12 for an illustration of this sequence.

The Full-Bridge mode does not provide dead-band delay. As one output is modulated at a time, dead-band delay is generally not required. There is a situation where dead-band delay is required. This situation occurs when both of the following conditions are true:

- 1. The direction of the PWM output changes when the duty cycle of the output is at or near 100%.
- 2. The turn off time of the power switch, including the power device and driver circuit, is greater than the turn on time.

Figure 10-13 shows an example of the PWM direction changing from forward to reverse, at a near 100% duty cycle. In this example, at time t1, the output P1A and P1D become inactive, while output P1C becomes active. Since the turn off time of the power devices is longer than the turn on time, a shoot-through current will flow through power devices QC and QD (see Figure 10-10) for the duration of 't'. The same phenomenon will occur to power devices QA and QB for PWM direction change from reverse to forward.

If changing PWM direction at high duty cycle is required for an application, two possible solutions for eliminating the shoot-through current are:

- 1. Reduce PWM duty cycle for one PWM period before changing directions.
- 2. Use switch drivers that can drive the switches off faster than they can drive them on.

Other options to prevent shoot-through current may exist.

FIGURE 10-12: EXAMPLE OF PWM DIRECTION CHANGE



When changing directions, the P1A and P1C signals switch before the end of the current PWM cycle.
 modulated P1B and P1D signals are inactive at this time. The length of this time is four Timer2 counts.

- Note 1: The auto-shutdown condition is a levelbased signal, not an edge-based signal. As long as the level is present, the autoshutdown will persist.
 - 2: Writing to the ECCPASE bit is disabled while an auto-shutdown condition persists.
 - 3: Once the auto-shutdown condition has been removed and the PWM restarted (either through firmware or auto-restart), the PWM signal will always restart at the beginning of the next PWM period.

FIGURE 10-14: PWM AUTO-SHUTDOWN WITH FIRMWARE RESTART (PRSEN = 0)



10.4.5 AUTO-RESTART MODE

The Enhanced PWM can be configured to automatically restart the PWM signal once the auto-shutdown condition has been removed. Auto-restart is enabled by setting the PRSEN bit in the PWM1CON register.

If auto-restart is enabled, the ECCPASE bit will remain set as long as the auto-shutdown condition is active. When the auto-shutdown condition is removed, the ECCPASE bit will be cleared via hardware and normal operation will resume.

FIGURE 10-15: PWM AUTO-SHUTDOWN WITH AUTO-RESTART ENABLED (PRSEN = 1)



11.0 VOLTAGE REGULATOR

The PIC16HV610/16HV616 include a permanent internal 5 volt (nominal) shunt regulator in parallel with the VDD pin. This eliminates the need for an external voltage regulator in systems sourced by an unregulated supply. All external devices connected directly to the VDD pin will share the regulated supply voltage and contribute to the total VDD supply current (ILOAD).

11.1 Regulator Operation

A shunt regulator generates a specific supply voltage by creating a voltage drop across a pass resistor RSER. The voltage at the VDD pin of the microcontroller is monitored and compared to an internal voltage reference. The current through the resistor is then adjusted, based on the result of the comparison, to produce a voltage drop equal to the difference between the supply voltage VUNREG and the VDD of the microcontroller. See Figure 11-1 for voltage regulator schematic.





An external current limiting resistor, RSER, located between the unregulated supply, VUNREG, and the VDD pin, drops the difference in voltage between VUNREG and VDD. RSER must be between RMAX and RMIN as defined by Equation 11-1.

EQUATION 11-1: RSER LIMITING RESISTOR

$$RMAX = \frac{(VUMIN - 5V)}{1.05 \cdot (4 MA + ILOAD)}$$

$$RMIN = \frac{(VUMAX - 5V)}{0.95 \cdot (50 \text{ MA})}$$

Where:

RMAX = maximum value of RSER (ohms)

RMIN = minimum value of RSER (ohms)

VUMIN = minimum value of VUNREG

VUMAX = maximum value of VUNREG

VDD = regulated voltage (5V nominal)

- ILOAD = maximum expected load current in mA including I/O pin currents and external circuits connected to VDD.
- 1.05 = compensation for +5% tolerance of RSER
- 0.95 = compensation for -5% tolerance of RSER

11.2 Regulator Considerations

The supply voltage VUNREG and load current are not constant. Therefore, the current range of the regulator is limited. Selecting a value for RSER must take these three factors into consideration.

Since the regulator uses the band gap voltage as the regulated voltage reference, this voltage reference is permanently enabled in the PIC16HV610/16HV616 devices.

RETFIE	Return from Interrupt
Syntax:	[label] RETFIE
Operands:	None
Operation:	$\begin{array}{l} TOS \to PC, \\ 1 \to GIE \end{array}$
Status Affected:	None
Description:	Return from Interrupt. Stack is POPed and Top-of-Stack (TOS) is loaded in the PC. Interrupts are enabled by setting Global Interrupt Enable bit, GIE (INTCON<7>). This is a two-cycle instruction.
Words:	1
Cycles:	2
Example:	RETFIE
	After Interrupt PC = TOS GIE = 1

RETLW	Return with literal in W				
Syntax:	[<i>label</i>] RETLW k				
Operands:	$0 \leq k \leq 255$				
Operation:	$k \rightarrow (W);$ TOS $\rightarrow PC$				
Status Affected:	None				
Description:	The W register is loaded with the eight-bit literal 'k'. The program counter is loaded from the top of the stack (the return address). This is a two-cycle instruction.				
Words:	1				
Cycles:	2				
Example:	CALL TABLE;W contains ;table offset ;value GOTO DONE				
TABLE	•				
DONE	• ADDWF PC ;W = offset RETLW k1 ;Begin table RETLW k2 ; • • RETLW kn ;End of table				
	Before Instruction				
	W = 0x07				
	After Instruction W = value of k8				
RETURN	Return from Subroutine				
Syntax:	[label] RETURN				
Operands:	None				
Operation:	$TOS \rightarrow PC$				
Status Affected:	None				
Description:	Return from subroutine. The stack is POPed and the top of the stack (TOS) is loaded into the program counter. This is a two-cycle instruction.				

15.9 DC Characteristics: PIC16F610/616/16HV610/616- I (Industrial) PIC16F610/616/16HV610/616 - E (Extended)

DC CHARACTERISTICS		Standard Operating Conditio Operating temperature		ditions (un -40°C ≤ -40°C ≤	itions (unless otherwise stated) -40°C \leq TA \leq +85°C for industrial -40°C \leq TA \leq +125°C for extended		
Param No.	Sym	Characteristic	Min	Тур†	Мах	Units	Conditions
D101*	COSC2	Capacitive Loading Specs on Output Pins OSC2 pin	_	_	15	pF	In XT, HS and LP modes when external clock is used to drive OSC1
D101A*	Сю	All I/O pins	—	_	50	pF	
		Program Flash Memory					
D130	Eр	Cell Endurance	10K	100K	—	E/W	$-40^{\circ}C \leq TA \leq +85^{\circ}C$
D130A	ED	Cell Endurance	1K	10K	—	E/W	+85°C \leq TA \leq +125°C
D131	Vpr	VDD for Read	VMIN	_	5.5	V	VMIN = Minimum operating voltage
D132	VPEW	VDD for Erase/Write	4.5	—	5.5	V	
D133	TPEW	Erase/Write cycle time	—	2	2.5	ms	
D134	Tretd	Characteristic Retention	40	_		Year	Provided no other specifications are violated

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: In RC oscillator configuration, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended to use an external clock in RC mode.

15.10 Thermal Considerations

Standard Operating Conditions (unless otherwise stated)Operating temperature $-40^{\circ}C \le TA \le +125^{\circ}C$						
Param No.	Sym	Characteristic	Тур	Units	Conditions	
TH01	θJA	Thermal Resistance	70*	C/W	14-pin PDIP package	
		Junction to Ambient	85.0*	C/W	14-pin SOIC package	
			100*	C/W	14-pin TSSOP package	
			37*	C/W	16-pin QFN 4x4mm package	
TH02	θJC	Thermal Resistance	32.5*	C/W	14-pin PDIP package	
		Junction to Case	31.0*	C/W	14-pin SOIC package	
			31.7*	C/W	14-pin TSSOP package	
			2.6*	C/W	16-pin QFN 4x4mm package	
TH03	TDIE	Die Temperature	150*	С		
TH04	PD	Power Dissipation	—	W	PD = PINTERNAL + PI/O	
TH05	PINTERNAL	Internal Power Dissipation	—	W	PINTERNAL = IDD x VDD (NOTE 1)	
TH06	Pi/o	I/O Power Dissipation	—	W	$PI/O = \Sigma (IOL * VOL) + \Sigma (IOH * (VDD - VOH))$	
TH07	Pder	Derated Power	_	W	Pder = PDmax (Tdie - Ta)/θja (NOTE 2)	
*	These para	meters are characterized but n	ot tested			

These parameters are characterized but not tested.

Note 1: IDD is current to run the chip alone without driving any load on the output pins.

2: TA = Ambient Temperature.



FIGURE 15-8: RESET, WATCHDOG TIMER, OSCILLATOR START-UP TIMER AND POWER-UP TIMER TIMING





TABLE 15-4:RESET, WATCHDOG TIMER, OSCILLATOR START-UP TIMER, POWER-UP TIMER
AND BROWN-OUT RESET PARAMETERS

Standard Operating Conditions (unless otherwise stated)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$								
Param No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions	
30	TMCL	MCLR Pulse Width (low)	2 5			μs μs	VDD = 5V, -40°C to +85°C VDD = 5V, -40°C to +125°C	
31*	Twdt	Watchdog Timer Time-out Period (No Prescaler)	10 10	20 20	30 35	ms ms	VDD = 5V, -40°C to +85°C VDD = 5V, -40°C to +125°C	
32	Tost	Oscillation Start-up Timer Period ^(1, 2)	_	1024		Tosc	(NOTE 3)	
33*	TPWRT	Power-up Timer Period	40	65	140	ms		
34*	Tioz	I/O High-impedance from MCLR Low or Watchdog Timer Reset	_	_	2.0	μs		
35*	VBOR	Brown-out Reset Voltage	2.0	2.15	2.3	V	(NOTE 4)	
36*	VHYST	Brown-out Reset Hysteresis		100	_	mV		
37*	TBOR	Brown-out Reset Minimum Detection Period	100			μS	$VDD \leq VBOR$	

Legend: TBD = To Be Determined

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

- 2: By design.
- 3: Period of the slower clock.
- **4:** To ensure these voltage tolerances, VDD and VSS must be capacitivey decoupled as close to the device as possible. 0.1 μF and 0.01 μF values in parallel are recommended.

Note 1: Instruction cycle period (TCY) equals four times the input oscillator time base period. All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. All devices are tested to operate at "min" values with an external clock applied to the OSC1 pin. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.



FIGURE 16-26: PIC16HV610/616 IDD EXTRC (4 MHz) vs. VDD











FIGURE 16-41: SCHMITT TRIGGER INPUT THRESHOLD VIN vs. VDD OVER TEMPERATURE











Example

17.0 PACKAGING INFORMATION

17.1 Package Marking Information

14-Lead PDIP



* Standard PIC[®] device marking consists of Microchip part number, year code, week code, and traceability code. For PIC[®] device marking beyond this, certain price adders apply. Please check with your Microchip Sales Office. For QTP devices, any special marking adders are included in QTP price.

16-Lead Plastic Quad Flat, No Lead Package (ML) – 4x4x0.9 mm Body [QFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimensio	n Limits	MIN	NOM	MAX	
Number of Pins	Ν	16			
Pitch	е	0.65 BSC			
Overall Height	Α	0.80	0.90	1.00	
Standoff	A1	0.00	0.02	0.05	
Contact Thickness	A3	0.20 REF			
Overall Width	Е	4.00 BSC			
Exposed Pad Width	E2	2.50	2.65	2.80	
Overall Length	D	4.00 BSC			
Exposed Pad Length	D2	2.50	2.65	2.80	
Contact Width	b	0.25	0.30	0.35	
Contact Length	L	0.30	0.40	0.50	
Contact-to-Exposed Pad		0.20	-	-	

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated.
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

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